



SN65HVD05, SN65HVD06 SN75HVD05, SN65HVD07 SN75HVD06, SN75HVD07

SLLS533E -MAY 2002-REVISED AUGUST 2009

HIGH OUTPUT RS-485 TRANSCEIVERS

Check for Samples: SN65HVD05, SN65HVD06, SN75HVD05, SN65HVD07, SN75HVD06, SN75HVD07

FEATURES

www.ti.com

- Minimum Differential Output Voltage of 2.5 V Into a 54-Ω Load
- Open-Circuit, Short-Circuit, and Idle-Bus Failsafe Receiver
- 1/8th Unit-Load Option Available (Up to 256 Nodes on the Bus)
- Bus-Pin ESD Protection Exceeds 16 kV HBM
- Driver Output Slew Rate Control Options
- Electrically Compatible With ANSI TIA/EIA-485-A Standard
- Low-Current Standby Mode: 1 µA Typical
- Glitch-Free Power-Up and Power-Down Protection for Hot-Plugging Applications
- Pin Compatible With Industry Standard SN75176

APPLICATIONS

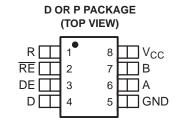
- Data Transmission Over Long or Lossy Lines or Electrically Noisy Environments
- Profibus Line Interface
- Industrial Process Control Networks
- · Point-of-Sale (POS) Networks
- Electric Utility Metering
- Building Automation
- Digital Motor Control

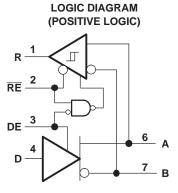
DIFFERENTIAL OUTPUT VOLTAGE vs DIFFERENTIAL OUTPUT CURRENT $T_A = 25^{\circ}C$ DE at Vcc - Differential Output Voltage - V D at V_{CC} 60 O Load $V_{CC} = 5 V$ 3.5 30 Ω Load Line 2.5 2 1.5 0 40 60 I_{OD} - Differential Output Current - mA

DESCRIPTION

SN65HVD05. SN75HVD05. SN65HVD06. SN75HVD06, SN65HVD07, SN75HVD07 and combine a 3-state differential line driver and differential line receiver. They are designed for balanced data transmission and interoperate with ANSI TIA/EIA-485-A and ISO 8482E standard-compliant devices. The driver is designed to provide a differential output voltage greater than that required by these standards for increased noise margin. The drivers and receivers have active-high and active-low enables respectively, which can be externally connected together to function as direction control.

The driver differential outputs and receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or not powered. These devices feature wide positive and negative common-mode voltage ranges, making them suitable for party-line applications.







Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION⁽¹⁾

				PART NUMBER ⁽²⁾		MARK	ED AS
SIGNALING RATE	UNIT LOAD	DRIVER OUTPUT SLOPE CONTROL	T _A			PLASTIC DUAL-IN-LINE PACKAGE (PDIP)	SMALL OUTLINE IC (SOIC) PACKAGE
40 Mbps	1/2	No		SN65HVD05D	SN65HVD05P	65HVD05	VP05
10 Mbps	1/8	Yes	–40°C to 85°C	SN65HVD06D	SN65HVD06P	65HVD06	VP06
1 Mbps	1/8	Yes		SN65HVD07D	SN65HVD07P	65HVD07	VP07
40 Mbps	1/2	No		SN75HVD05D	SN75HVD05P	75HVD05	VN05
10 Mbps	1/8	Yes	0°C to 70°C	SN75HVD06D	SN75HVD06P	75HVD06	VN06
1 Mbps	1/8	Yes		SN75HVD07D	SN75HVD07P	75HVD07	VN07

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

PACKAGE DISSIPATION RATINGS

(See Figure 12 and Figure 13)

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D ⁽²⁾	710 mW	5.7 mW/°C	455 mW	369 mW
D ⁽³⁾	1282 mW	10.3 mW/°C	821 mW	667 mW
Р	1000 mW	8.0 m W/°C	640 mW	520 mW

- (1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.
- (2) Tested in accordance with the Low-K thermal metric definitions of EIA/JESD51-3
- (3) Tested in accordance with the High-K thermal metric definitions of EIA/JESD51-7

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted(1) (2)

			SN65HVD05, SN65HVD06, SN65HVD07 SN75HVD05, SN75HVD06, SN75HVD07		
Supply voltage range, Vo	DC .		–0.3 V to 6 V		
Voltage range at A or B			–9 V to 14 V		
Input voltage range at D,	DE, R or RE		–0.5 V to V _{CC} + 0.5 V		
Voltage input range, transient pulse, A and B, through 100 Ω (see Figure 11)			–50 V to 50 V		
Receiver output current,	I _O		-11 mA to 11mA		
	Livean hady model(3)	A, B, and GND	16 kV		
Electrostatic discharge	Human body model ⁽³⁾	All pins	4 kV		
	Charged-device model (4)	All pins	1 kV		
Continuous total power dissipation		See Dissipation Rating Table			

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under" recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101.

The D package is available taped and reeled. Add an R suffix to the device type (i.e., SN65HVD05DR).



RECOMMENDED OPERATING CONDITIONS

		MIN	NOM MAX	UNIT
Supply voltage, V _{CC}		4.5	5.5	V
Voltage at any bus terminal (separate	ely or common mode) V _I or V _{IC}	-7 ⁽¹⁾	12	V
High-level input voltage, V _{IH}	D, DE, RE	2		V
Low-level input voltage, V _{IL}	D, DE, RE		0.8	V
Differential input voltage, V _{ID} (see Fig	gure 7)	-12	12	V
I Park I and a standard and a standard a	Driver	-100		
High-level output current, I _{OH}	Receiver	-8		mA
	Driver		100	
Low-level output current, I _{OL}	Receiver		8	mA
	SN65HVD05			
	SN65HVD06	-40	85	°C
Operating free-air temperature, T _A	SN65HVD07			
	SN75HVD05			
	SN75HVD06	0	70	°C
	SN75HVD07			

⁽¹⁾ The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.

DRIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

PARAMETER			TEST CO	NDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT		
V _{IK}	Input clamp voltage		I _I = -18 mA		-1.5			V		
			No Load				V_{CC}			
$ V_{OD} $	Differential output voltage		$R_L = 54 \Omega$, See Figur	e 4	2.5			V		
			$V_{\text{test}} = -7 \text{ V to } 12 \text{ V}, 3$	See Figure 2	2.2					
$\Delta V_{OD} $	Change in magnitude of differential voltage	output	See Figure 4 and Fig	ure 2	-0.2		0.2	V		
V _{OC(SS)}	Steady-state common-mode output	voltage			2.2		3.3	V		
$\Delta V_{OC(SS)}$	Change in steady-state common-mooutput voltage	ode	See Figure 3		See Figure 3		-0.1		0.1	V
		HVD05				600				
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage		See Figure 3		500		mV			
output voltage	HVD07				900					
l _{OZ}	High-impedance output current		See receiver input currents							
	Input ourrent	D			-100		0			
l _l	Input current	DE			0		100	μA		
I _{OS}	Short-circuit output current		$-7 \text{ V} \leq \text{V}_{\text{O}} \leq 12 \text{ V}$		-250		250	mA		
C _(diff)	Differential output capacitance		$V_{ID} = 0.4 \sin (4E6\pi t)$	+ 0.5 V, DE at 0 V		16		pF		
			RE at V _{CC} , D and DE at V _{CC} , No load	Receiver disabled and driver enabled		9	15	mA		
I _{CC} Supply current			RE at V _{CC} , D at V _{CC} DE at 0 V, No load	Receiver disabled and driver disabled (standby)		1	5	μA		
			RE at 0 V, D and DE at V _{CC} , No load	Receiver enabled and driver enabled		9	15	mA		

⁽¹⁾ All typical values are at 25°C and with a 5-V supply.



DRIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
		HVD05			6.5	11	
t _{PLH}	Propagation delay time, low-to-high-level output	HVD06			27	40	ns
		HVD07			250	400	
		HVD05			6.5	11	
t _{PHL}	Propagation delay time, high-to-low-level output	HVD06			27	40	ns
		HVD07			250	400	
		HVD05		2.7	3.6	6	
t _r	Differential output signal rise time	HVD06		18	28	55	ns
		HVD07	$R_L = 54 \Omega, C_L = 50 pF,$	150	300	450	
		HVD05	See Figure 4	2.7	3.6	6	
t _f	Differential output signal fall time	HVD06	_	18	28	55	ns
		HVD07		150	300	450	
		HVD05	_			2	
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH})	HVD06	_			2.5	ns
- (1)		HVD07	_			10	
		HVD05	_			3.5	
t _{sk(pp)} (2)	Part-to-part skew	HVD06	_			14	ns
- 417		HVD07				100	
		HVD05	\overline{RE} at 0 V, R ₁ = 110 Ω ,			25	
t _{PZH1}	Propagation delay time, high-impedance-to-high-level output	HVD06				45	ns
	nign-impedance-to-nign-iever output	HVD07		250			
		HVD05	See Figure 5	25		25	ns
t _{PHZ}	Propagation delay time,	HVD06		60		60	
	high-level-to-high-impedance output	HVD07		250		250	
		HVD05				15	
t _{PZL1}	Propagation delay time, high-impedance-to-low-level	HVD06				45	ns
	output	HVD07	\overline{RE} at 0 V, R _L = 110 Ω ,			200	
		HVD05	See Figure 6			14	
t_{PLZ}	Propagation delay time, low-level-to-high-impedance	HVD06	_			90	ns
	output	HVD07				550	
t _{PZH2}	Propagation delay time, standby-to-high-level output	I	$R_L = 110\Omega$, \overline{RE} at 3 V, See Figure 5			6	μs
t _{PZL2}	Propagation delay time, standby-to-low-level output		$R_L = 110 \Omega$, \overline{RE} at 3 V, See Figure 6			6	μs

⁽¹⁾ All typical values are at 25°C and with a 5-V supply.

⁽²⁾ t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.



RECEIVER ELECTRICAL CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

	PARAMETER		TI	EST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT														
$V_{\text{IT+}}$	Positive-going inputhreshold voltage	ut	$I_O = -8 \text{ mA}$					-0.01	V														
$V_{\text{IT-}}$	Negative-going inp threshold voltage	out	I _O = 8 mA			-0.2			V														
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})	•					35		mV														
V _{IK}	Enable-input clam	p voltage	I _I = -18 mA			-1.5			V														
V _{OH}	High-level output v	/oltage	V _{ID} = 200 mV,	$I_{OH} = -8 \text{ mA},$	See Figure 7	4			V														
V_{OL}	Low-level output v	oltage	$V_{ID} = -200 \text{ mV},$	$I_{OL} = 8 \text{ mA},$	See Figure 7			0.4	V														
I_{OZ}	High-impedance-s output current	tate	$V_O = 0$ or V_{CC}	$\overline{\text{RE}}$ at V_{CC}		-1		1	μΑ														
				V_A or $V_B = 12 V$			0.23	0.5															
			HVD05	Other inputat 0 V	V_A or $V_B = 12 V$,	$V_{CC} = 0 V$		0.3	0.5	mA													
			Other inputat 0 v	V_A or $V_B = -7 \text{ V}$		-0.4	0.13		ША														
I.			Rus input current		V_A or $V_B = -7 V$,	$V_{CC} = 0 V$	-0.4	0.15															
I _I		bus input current	bus input current			V_A or $V_B = 12 V$			0.06	0.1													
		HVD06 HVD07	Other inputat 0 V	V_A or $V_B = 12 V$,	$V_{CC} = 0 V$		0.08	0.13	mA														
			HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	HVD07	Other inputat 0 v	V_A or $V_B = -7 \text{ V}$		-0.1	0.05		ША
				V_A or $V_B = -7 V$,	$V_{CC} = 0 V$	-0.05	0.03																
I _{IH}	High-level input cu RE	ırrent,	V _{IH} = 2 V			-60	26.4		μΑ														
I _{IL}	Low-level input cu	rrent, RE	$V_{IL} = 0.8 \ V$			-60	27.4		μΑ														
$C_{\text{(diff)}}$	Differential input capacitance		$V_I = 0.4 \sin (4E6\pi t) + 0.$	V _I = 0.4 sin (4E6πt) + 0.5 V, DE at 0 V			16		pF														
			RE at 0 V, D and DE at 0 V, No load	Receiver enabled and	d driver disabled		5	10	mA														
I _{CC}			$\overline{\text{RE}}$ at V_{CC} , DE at 0 V, D at V_{CC} , No load	Receiver disabled an (standby)	d driver disabled		1	5	μΑ														
			RE at 0 V, D and DE at V _{CC} , No load	Receiver enabled and	d driver enabled		9	15	mA														

⁽¹⁾ All typical values are at 25°C and with a 5-V supply.



RECEIVER SWITCHING CHARACTERISTICS

over operating free-air temperature range unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT	
t _{PLH}	Propagation delay time, low-to-high-level output 1/2 UL	HVD05			14.6	25	ns	
t _{PHL}	Propagation delay time, high-to-low-level output 1/2 UL	HVD05			14.6	25	ns	
	Dranagation delay time low to high layer output 1/9 III	HVD06			55	70		
t _{PLH}	Propagation delay time, low-to-high-level output 1/8 UL	HVD07			55	70	ns	
	Depression delections high to level output 4/0.11	HVD06			55	70		
t _{PHL}	Propagation delay time, high-to-low-level output 1/8 UL	HVD07	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$		55	70	ns	
		HVD05	C _L = 15 pF, See Figure 8		<u> </u>	2		
t _{sk(p)}	Pulse skew (t _{PHL} - t _{PLH})	HVD06				4.5	ns	
		HVD07				4.5		
		HVD05				6.5	ns	
t _{sk(pp)} (2)	Part-to-part skew	HVD06				14		
		HVD07				14		
t _r	Output signal rise time		C _L = 15 pF,		2	3		
t _f	Output signal fall time		See Figure 8		2	3	ns	
t _{PZH1}	Output enable time to high level					10	<u> </u>	
t _{PZL1}	Output enable time to low level		$C_L = 15 \text{ pF},$			10		
t _{PHZ}			DE at 3 V, See Figure 9			15	ns	
t _{PLZ}	Output disable time from low level		3			15	İ	
t _{PZH2}			$C_L = 15 \text{ pF, DE at 0,}$			6		
t _{PZL2}	Propagation delay time, standby-to-low-level output		See Figure 10		•	6	μs	

⁽¹⁾ All typical values are at 25°C and with a 5-V supply.

PARAMETER MEASUREMENT INFORMATION

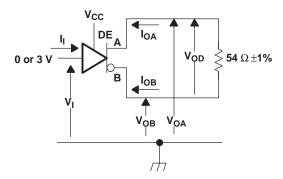


Figure 1. Driver V_{OD} Test Circuit and Voltage and Current Definitions

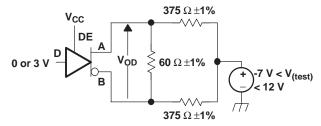
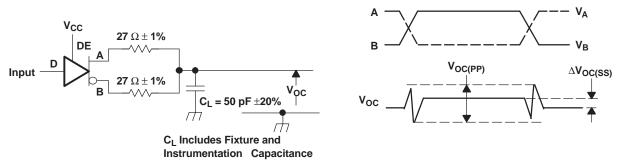


Figure 2. Driver V_{OD} With Common-Mode Loading Test Circuit

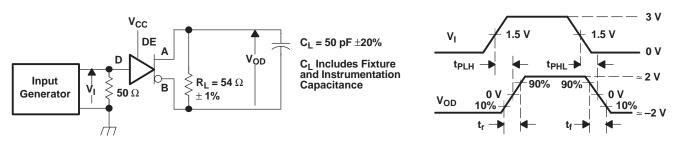
⁽²⁾ t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.





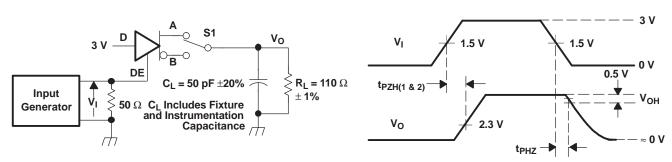
Input: PRR = 500 kHz, 50% Duty Cycle, t_r <6ns, t_f <6ns, Z_O = 50 Ω

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



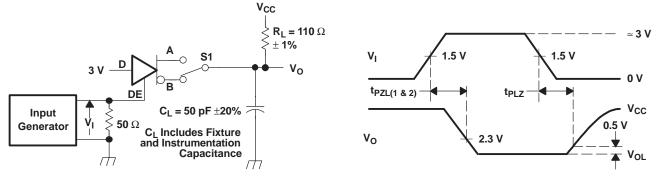
Generator: PRR = 500 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z_o = 50 Ω

Figure 4. Driver Switching Test Circuit and Voltage Waveforms



Generator: PRR = 100 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z_o = 50 Ω

Figure 5. Driver High-Level Enable and Disable Time Test Circuit and Voltage Waveforms



Generator: PRR = 100 kHz, 50% Duty Cycle, t_r <6 ns, t_f <6 ns, Z_o = 50 Ω

Figure 6. Driver Low-Level Output Enable and Disable Time Test Circuit and Voltage Waveforms



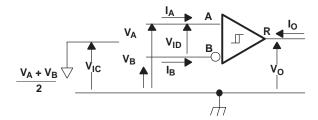


Figure 7. Receiver Voltage and Current Definitions

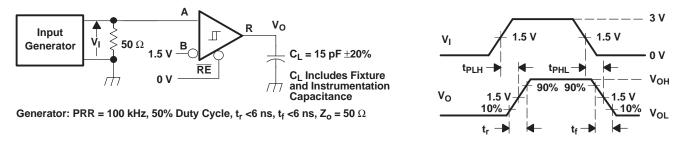


Figure 8. Receiver Switching Test Circuit and Voltage Waveforms



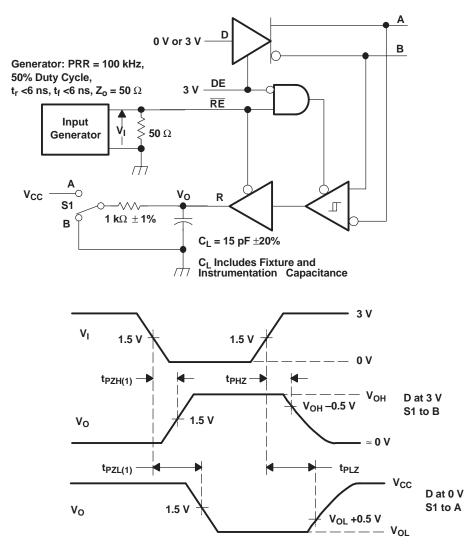


Figure 9. Receiver Enable and Disable Time Test Circuit and Voltage Waveforms With Drivers Enabled



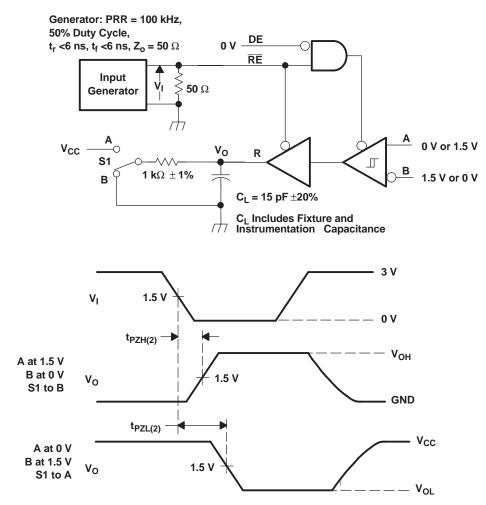
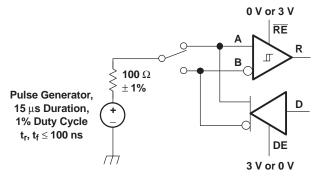


Figure 10. Receiver Enable Time From Standby (Driver Disabled)



NOTE: This test is conducted to test survivability only. Data stability at the R output is not specified.

Figure 11. Test Circuit, Transient Over Voltage Test



FUNCTION TABLES

Table 1. DRIVER

INPUT	ENABLE	OUT	PUTS
D	DE	Α	В
Н	Н	Н	Г
L	Н	L	Н
X	L	Z	Z
Open	Н	Н	L
X	Open	Z	Z

Table 2. RECEIVER (1)

DIFFERENTIAL INPUTS	ENABLE	OUTPUT
$V_{ID} = V_A - V_B$	RE	R
V _{ID} ≤ -0.2 V	L	L
$V_{ID} \le -0.2 \text{ V}$ -0.2 V < $V_{ID} < -0.01 \text{ V}$	L	?
-0.01 V≤ V _{ID}	L	Н
X	H	Z
Open Circuit	L	Н
Short Circuit	L	Н
IDLE Bus	L	Н
X	Open	Z

(1) H = high level; L = low level; Z = high impedance; X = irrelevant;? = indeterminate

Receiver Failsafe

The differential receiver is "failsafe" to invalid bus states caused by:

- · open bus conditions such as a disconnected connector,
- shorted bus conditions such as cable damage shorting the twisted-pair together, or
- idle bus conditions that occur when no driver on the bus is actively driving

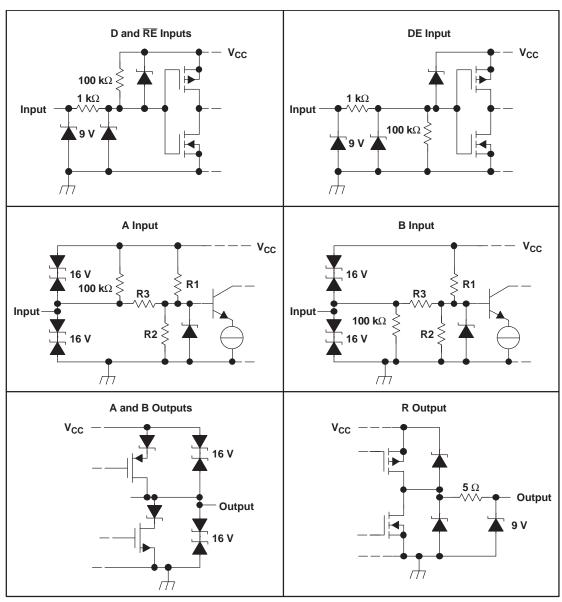
In any of these cases, the differential receiver outputs a failsafe logic High state, so that the output of the receiver is not indeterminate.

Receiver failsafe is accomplished by offsetting the receiver thresholds so that the "input indeterminate" range does not include zero volts differential. To comply with the RS-422 and RS-485 standards, the receiver output must output a High when the differential input V_{ID} is more positive than +200 mV, and must output a Low when the V_{ID} is more negative than -200 mV. The receiver parameters which determine the failsafe performance are V_{IT+} and V_{IT-} and V_{HYS} . As seen in the Receiver Electrical Characteristics table, differential signals more negative than -200 mV will always cause a Low receiver output. Similarly, differential signals more positive than +200 mV will always cause a High receiver output.

When the differential input signal is close to zero, it will still be above the V_{IT_+} threshold, and the receiver output is High. Only when the differential input is more negative than V_{IT_-} will the receiver output transition to a Low state. So, the noise immunity of the receiver inputs during a bus fault condition includes the receiver hysteresis value V_{HYS} (the separation between V_{IT_+} and V_{IT_-}) as well as the value of V_{IT_+} .



EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



	R1/R2	R3
	K I/KZ	1/3
SN65HVD05	9 k Ω	45 k Ω
SN65HVD06	36 k Ω	180 k Ω
SN65HVD07	36 k Ω	180 k Ω



TYPICAL CHARACTERISTICS



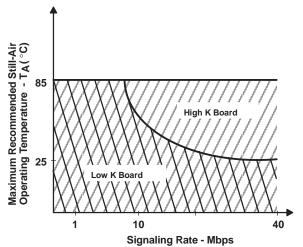
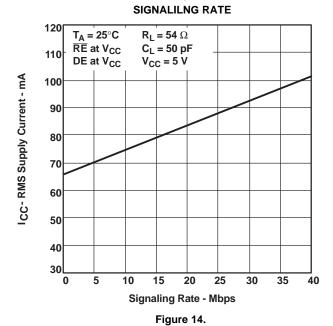


Figure 12.

HVD05 RMS SUPPLY CURRENT vs



HVD06
MAXIMUM RECOMMENDED STILL-AIR
OPERATING TEMPERATURE
vs
SIGNALING RATE

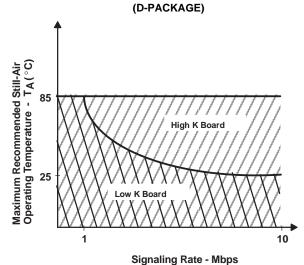
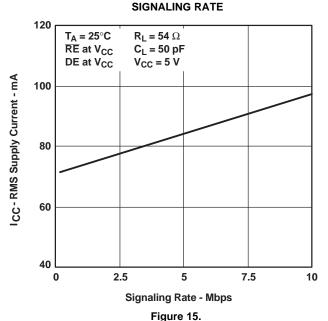


Figure 13.

HVD06
RMS SUPPLY CURRENT vs



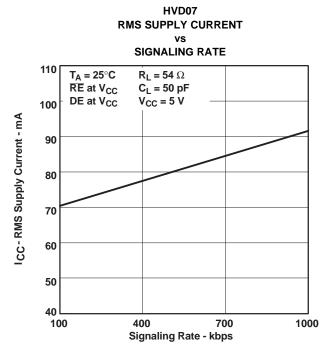


TYPICAL CHARACTERISTICS (continued)

-150

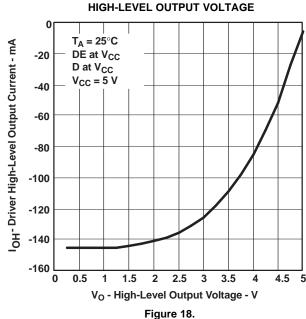
-200

-7 -6 -5 -4 -3 -2 -1



DRIVER HIGH-LEVEL OUTPUT CURRENT vs

Figure 16.



BUS INPUT VOLTAGE 250 $T_A = 25^{\circ}C$ DE at 0 V 200 $V_{CC} = 5 V$ 150 I - Bus Input Current - μA 100 HVD05 50 0 HVD06 HVD07 -50 -100

BUS INPUT CURRENT

V_I - Bus Input Voltage - V Figure 17.

0 1 2 3 4 5 6 7 8 9 1011 12

DRIVER LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE

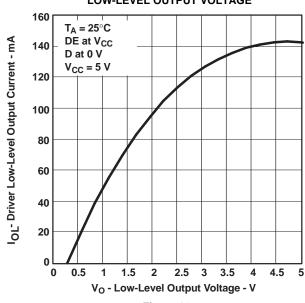


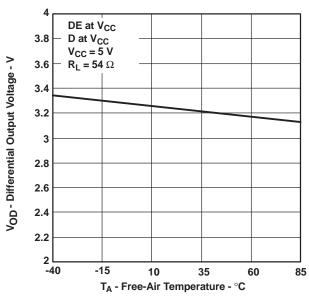
Figure 19.



TYPICAL CHARACTERISTICS (continued)

DIFFERENTIAL OUTPUT VOLTAGE

FREE-AIR TEMPERATURE



DRIVER OUTPUT CURRENT

vs

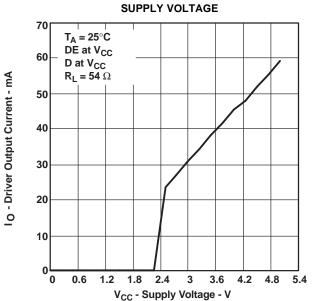


Figure 21.

DIFFERENTIAL OUTPUT VOLTAGE

Figure 20.

DIFFERENTIAL OUTPUT CURRENT

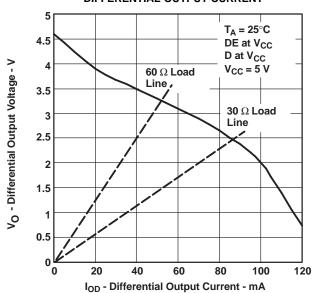


Figure 22.

ENABLE TIME

COMMON-MODE VOLTAGE (SEE Figure 24)

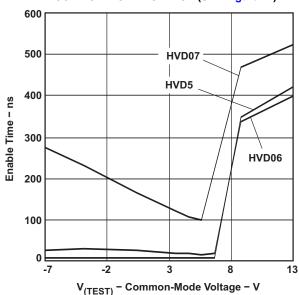


Figure 23.



TYPICAL CHARACTERISTICS (continued)

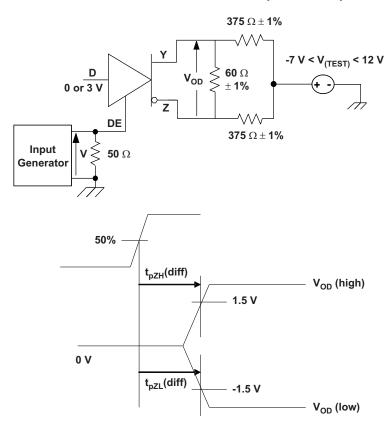
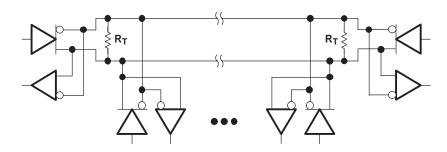


Figure 24. Driver Enable Time From DE to $V_{\rm OD}$

The time $t_{pZL}(x)$ is the measure from DE to $V_{OD}(x)$. V_{OD} is valid when it is greater than 1.5 V.



APPLICATION INFORMATION



Device	Number of Devices on Bus
HVD05	64
HVD06	256
HVD07	256

NOTE: The line should be terminated at both ends with its characteristic impedance ($R_T = Z_O$). Stub lengths off the main line should be kept as short as possible.

Figure 25. Typical Application Circuit

REVISION HISTORY

Changes from Revision D (July 2006) to Revision E						
•	Added IDLE Bus to the Receivers Function Table		1			
•	Added the Receiver Failsafe paragraph.	<i>•</i>	1			



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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN65HVD05D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD05DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD05DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD05DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD05P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65HVD05PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65HVD06D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD06DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD06DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD06DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD06P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65HVD06PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65HVD07D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD07DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD07DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD07DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65HVD07P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN65HVD07PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD05D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD05DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD05P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD05PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD06D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD06DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD06DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

PACKAGE OPTION ADDENDUM

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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75HVD06DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD06P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD06PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD07D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD07DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD07DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD07DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75HVD07P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75HVD07PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD05DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65HVD06DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN65HVD07DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75HVD06DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SN75HVD07DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD05DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65HVD06DR	SOIC	D	8	2500	340.5	338.1	20.6
SN65HVD07DR	SOIC	D	8	2500	340.5	338.1	20.6
SN75HVD06DR	SOIC	D	8	2500	340.5	338.1	20.6
SN75HVD07DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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